

Inverting Charge Pump Voltage Doublers with Active Low Shutdown

Features

- Small 8-Pin MSOP Package
- Operates from 1.8V to 5.5V
- 120 Ohms (typ) Output Resistance
- 99% Voltage Conversion Efficiency
- · Only 3 External Capacitors Required
- · Power-Saving Shutdown Mode
- · Low Active Supply Current
- 95μA (typ) for TC3682
- 225μA (typ) for TC3683
- 700µA (typ) for TC3684
- · Fully Compatible with 1.8V Logic Systems

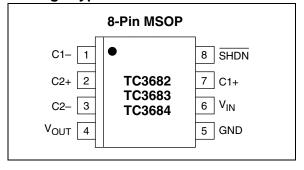
Applications

- LCD Panel Bias
- · Cellular Phones PA Bias
- Pagers
- PDAs, Portable Data Loggers
- · Battery-Powered Devices

Device Selection Table

Part Number	Package	Osc. Freq. (kHz)	Operating Temp. Range
TC3682EUA	8-Pin MSOP	12	-40°C to +85°C
TC3683EUA	8-Pin MSOP	35	-40°C to +85°C
TC3684EUA	8-Pin MSOP	125	-40°C to +85°C

Package Type



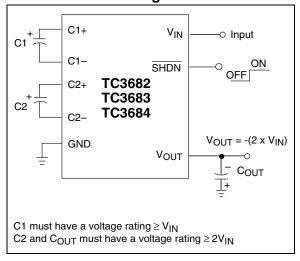
General Description

The TC3682/TC3683/TC3684 are CMOS charge pump converters that provide an inverted doubled output from a single positive supply. An on-board oscillator provides the clock and only three external capacitors are required for full circuit implementation. Switching frequencies are 12kHz for the TC3682, 35kHz for the TC3683, and 125kHz for the TC3684. When the \overline{SHDN} pin is held at a logic low, the device goes into a very low power mode of operation consuming less than $1\mu A$ (typ) of supply current.

Low output source impedance (typically 120Ω), provides output current up to 10mA. The TC3682/TC3683/TC3684 feature a 1.8V to 5.5V operating voltage range and high efficiency, which make them an ideal choice for a wide variety of applications requiring a negative doubled voltage derived from a single positive supply (for example: generation of -7.2V from a +3.6V lithium cell or -10V generated from a +5V logic supply).

The minimum external part count, small physical size and shutdown mode feature make this family of products useful for a wide variety of negative bias power supply applications.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings*

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*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

TC3682/TC3683/TC3684 ELECTRICAL SPECIFICATIONS

Electrical Characteristics: $T_A = -40$ °C to +85 °C, $V_{IN} = +5V$, $C1 = C2 = 3.3 \mu F$ (TC3682), $C1 = C2 = 1 \mu F$ (TC3683), C1 = C2 = 0.33 μ F (TC3684), SHDN = GND, Typical values are at T_{Δ} = +25°C **Symbol Parameter** Min Тур Max Units **Device Test Conditions** SHDN = V_{IN} Supply Current 95 160 TC3682 I_{DD} 225 TC3683 SHDN = VIN 480 700 1500 TC3684 SHDN = VIN Shutdown Supply Current 0.5 2 ΑII SHDN = GND, V_{IN} = +5V μΑ I_{SHDN} Minimum Supply Voltage 1.8 ٧ ΑII V_{MIN} $R_{LOAD} = 1k\Omega$ 5.5 ٧ ΑII Maximum Supply Voltage $R_{LOAD} = 1k\Omega$ V_{MAX} TC3682 Oscillator Frequency 8.4 12 15.6 kHz Fosc 24.5 35 45.5 TC3683 65 125 170 TC3684 ٧ ΑII V_{IH} SHDN Input Logic High 1.4 $V_{IN} = V_{MIN}$ to V_{MAX} V_{IL} SHDN Input Logic Low 0.4 ٧ ΑII $V_{IN} = V_{MIN}$ to V_{MAX} Voltage Conversion Efficiency ΑII V_{EFF} 95 99 % $R_{LOAD} = \infty$ Output Resistance ΑII 120 170 Ω $I_{LOAD} = 0.5 mA$ to 10mA (Note 1) R_{OUT} TC3682 Twk Wake-up Time From Shutdown Mode 1800 μsec $R_{LOAD} = 2k\Omega$ 600 TC3683 TC3684 200

Note 1: Capacitor contribution is approximately 20% of the output impedance (ESR = 1/ pump frequency x capacitance).

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

Pin No. (8-Pin MSOP)	Symbol	Description
1	C1-	C1 commutation capacitor negative terminal.
2	C2+	C2 commutation capacitor positive terminal.
3	C2-	C2 commutation capacitor negative terminal.
4	V _{OUT}	Doubling inverting charge pump output (-2 x V _{IN}).
5	GND	Ground.
6	V _{IN}	Positive power supply input.
7	C1+	C1 commutation capacitor positive terminal.
8	SHDN	Shutdown input (active low).

3.0 DETAILED DESCRIPTION

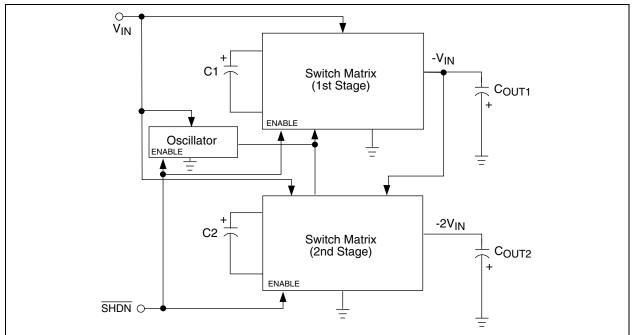
The TC3682/TC3683/TC3684 inverting charge pumps perform a -2x multiplication of the voltage applied to the V_{IN} pin. Conversion is performed using two *synchronous* switching matrices and three external capacitors. When the shutdown input is held at a logic low, the device goes into a very low power mode of operation consuming less than $1\mu\text{A}$ of supply current.

Figure 3-1 is a block diagram representation of the TC3682/TC3683/TC3684 architecture. The first switching stage inverts the voltage present at V_{IN} and the second stage uses the '-V_{\text{IN}}' output generated from the first stage to produce the '-2X' output function from the second stage switching matrix.

Each device contains an on-board oscillator that synchronously controls the operation of the charge pump switching matrices. The TC3682 synchronously switches at 12kHz, the TC3683 synchronously switches at 35kHz, and the TC3684 synchronously switches at 125kHz. The different oscillator frequencies for this device family allow the user to trade-off capacitor size versus supply current. Faster oscillators can use smaller external capacitors, but will consume more supply current (see Section 1.0 Electrical Characteristics).

When the shutdown input is in a low state, the oscillator and both switch matrices are powered off placing the TC3682/TC3683/TC3684 in the shutdown mode. When the V_{IN} supply input is powered from an external battery, the shutdown mode minimizes power consumption, which in turn will extend the life of the battery.

FIGURE 3-1: TC3682/TC3683/TC3684 ARCHITECTURE



4.0 APPLICATIONS INFORMATION

4.1 Output Voltage Considerations

The TC3682/TC3683/TC3684 perform inverting voltage conversions but do not provide any type of regulation. The output voltage will droop in a linear manner with respect to the output load current. The value of the equivalent output resistance of the '-V_{IN}' output is approximately 50Ω nominal at +25°C and V_{IN} = +5V. The value of the '-2V_{IN}' output is approximately 140 Ω nominal at +25°C and V_{IN} = +5V. In this particular case, '-V_{IN}' is approximately -5V and '-2V_{IN}' is approximately -10V at very light loads and each stage will droop according to the equation below:

 $V_{DROOP} = I_{OUT} \times R_{OUT}$

4.2 Capacitor Selection

In order to maintain the lowest output resistance and output ripple voltage, it is recommended that low ESR capacitors be used. Additionally, larger values of C1 and C2 will lower the output resistance and larger values of C_{OUT} will reduce output ripple.

Note: For proper charge pump operation, C1 must have a voltage rating greater than or equal to V_{IN} , while C2 and C_{OUT} must have a voltage rating greater than or equal to $2V_{IN}$.

Table 4-1 shows various values of C1/C2 and the corresponding output resistance values for V_{IN} = 5V @ +25°C.

Table 4-2 shows the output voltage ripple for various values of C_{OUT} (again assuming $V_{IN} = 5V @ +25^{\circ}C$). The V_{RIPPLE} values assume a 1mA output load current and a 0.1Ω ESR_{COUT}.

TABLE 4-1: OUTPUT RESISTANCE VS. C1/C2 (ESR = 0.1Ω)

C1, C2 (μF)	TC3682 R _{OUT} (Ω)	TC3683 R _{OUT} (Ω)	TC3684 R _{OUT} (Ω)
0.33	633	184	120
1	262	120	102
3.3	120	95	84

TABLE 4-2: OUTPUT VOLTAGE RIPPLE VS. C_{OUT} (ESR = 0.1 Ω) I_{OUT} = 1mA

C _{OUT} (μF)	TC3682 V _{RIPPLE} (mV)	TC3683 V _{RIPPLE} (mV)	TC3684 V _{RIPPLE} (mV)
0.33	192	60	27
1	63	21	16
3.3	17	8	7

4.3 Input Supply Bypassing

The V_{IN} input should be capacitively bypassed to reduce AC impedance and minimize noise effects due to the switching internal to the device. It is recommended that a large value capacitor (at least equal to C1) be connected from V_{IN} to GND for optimal circuit performance.

4.4 Shutdown Input

The TC3682/TC3683/TC3684 is enabled when \overline{SHDN} is high, and disabled when \overline{SHDN} is low. This input cannot be allowed to float. (If \overline{SHDN} is not required, see the TC2682/TC2683/TC2684 data sheet.) The \overline{SHDN} input should be limited to 0.3V above V_{IN} .

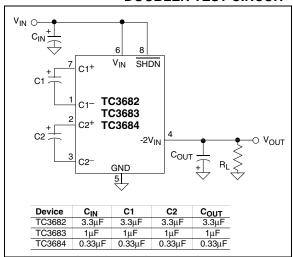
4.5 Inverting Voltage Doubler

The most common application for the TC3682/TC3683/ TC3684 devices is the inverting voltage doubler (Figure 4-1). This application uses three external capacitors: C1, C2 and C_{OUT} .

Note: A power supply bypass capacitor is recommended.

The output is equal to $-2V_{IN}$ plus any voltage drops due to loading. Refer to Table 4-1 and Table 4-2 for capacitor selection guidelines.

FIGURE 4-1: INVERTING VOLTAGE DOUBLER TEST CIRCUIT



4.6 Layout Considerations

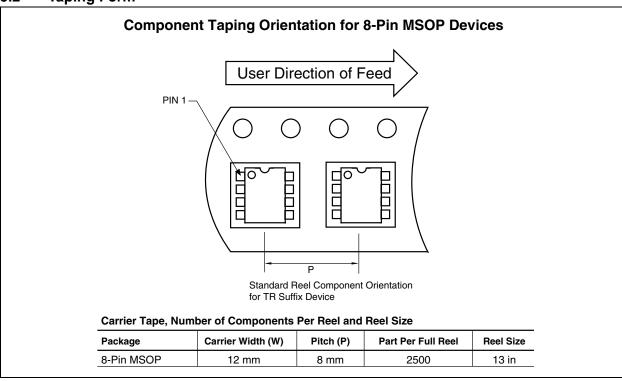
As with any switching power supply circuit, good layout practice is recommended. Mount components as close together as possible to minimize stray inductance and capacitance. Also use a large ground plane to minimize noise leakage into other circuitry.

5.0 PACKAGING INFORMATION

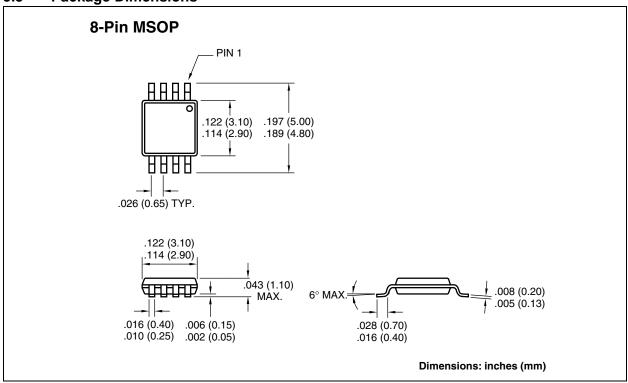
5.1 Package Marking Information

Package marking data not available at this time.

5.2 Taping Form



5.3 Package Dimensions



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2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: 480-792-7627 Web Address: http://www.microchip.com

Rocky Mountain

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7966 Fax: 480-792-7456

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New York

150 Motor Parkway, Suite 202 Hauppauge, NY 11788 Tel: 631-273-5305 Fax: 631-273-5335

San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

Toronto

6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

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Australia

Microchip Technology Australia Pty Ltd Suite 22, 41 Rawson Street Epping 2121, NSW Australia

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing Microchip Technology Consulting (Shanghai)

Co., Ltd., Beijing Liaison Office Unit 915 Bei Hai Wan Tai Bldg.

No. 6 Chaoyangmen Beidajie Beijing, 100027, No. China Tel: 86-10-85282100 Fax: 86-10-85282104

China - Chengdu

Microchip Technology Consulting (Shanghai) Co., Ltd., Chengdu Liaison Office Rm. 2401, 24th Floor, Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China Tel: 86-28-6766200 Fax: 86-28-6766599

China - Fuzhou

Microchip Technology Consulting (Shanghai) Co., Ltd., Fuzhou Liaison Office Unit 28F, World Trade Plaza No. 71 Wusi Road Fuzhou 350001, China Tel: 86-591-7503506 Fax: 86-591-7503521

China - Shanghai

Microchip Technology Consulting (Shanghai) Co., Ltd. Room 701, Bldg. B

Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051

Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

China - Shenzhen

Microchip Technology Consulting (Shanghai) Co., Ltd., Shenzhen Liaison Office Rm. 1315, 13/F, Shenzhen Kerry Centre, Renminnan Lu Shenzhen 518001, China Tel: 86-755-2350361 Fax: 86-755-2366086

Hong Kong

Microchip Technology Hongkong Ltd. Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

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Microchip Technology Inc. India Liaison Office Divvasree Chambers 1 Floor, Wing A (A3/A4) No. 11, O'Shaugnessey Road Bangalore, 560 025, India Tel: 91-80-2290061 Fax: 91-80-2290062

Japan

Microchip Technology Japan K.K. Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882

Tel: 82-2-554-7200 Fax: 82-2-558-5934

Singapore

Microchip Technology Singapore Pte Ltd. 200 Middle Road #07-02 Prime Centre Singapore, 188980

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